

## **isc** Silicon NPN Power Transistor

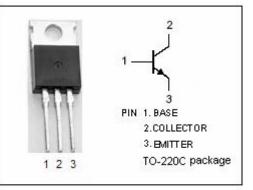
## 2SD856

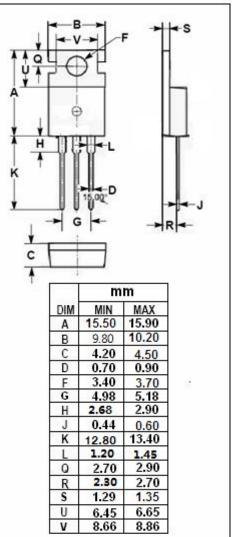
- · Collector-Emitter Breakdown Voltage-: V<sub>(BR)CEO</sub>= 60V(Min)
- Good Linearity of h<sub>FE</sub>
- Wide Area of Safe Operation
- · Complement to Type 2SB761
- · Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### **APPLICATIONS**

· Designed for AF power amplifier applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)						
SYMBOL	PARAMETER	VALUE	UNIT			
V <sub>CBO</sub>	Collector-Base Voltage	60	V			
V <sub>CEO</sub>	Collector-Emitter Voltage	60	V			
V <sub>EBO</sub>	Emitter-Base Voltage	6	V			
lc	Collector Current-Continuous	3	A			
Ісм	Collector Current-Peak	5	A			
Pc	Collector Power Dissipation @ Tc=25℃	35	W			
TJ	Junction Temperature	150	°C			
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C			





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# 2SD856

## **ELECTRICAL CHARACTERISTICS**

### $T_{c}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 10mA; I <sub>B</sub> = 0	60			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 3A; I <sub>B</sub> = 0.375A			1.2	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 3A; V <sub>CE</sub> = 4V			1.8	V
Iceo	Collector Cutoff Current	V <sub>CE</sub> = 30V; I <sub>B</sub> = 0			300	μA
I <sub>CES</sub>	Collector Cutoff Current	V <sub>CE</sub> = 60V; V <sub>BE</sub> = 0			200	μA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 6V; I <sub>C</sub> = 0			1	mA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 1A; V <sub>CE</sub> = 4V	40		250	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 3A; V <sub>CE</sub> = 4V	10			

#### Switching Times

ton	Turn-On Time			0.5	μ <b>S</b>
t <sub>off</sub>	Turn-Off Time		I <sub>C</sub> = 1A; I <sub>B1</sub> = I <sub>B2</sub> = 0.1A	3.0	μ <b>S</b>

#### h<sub>FE-1</sub> Classifications

R	Q	Р			
40-90	70-150	120-250			

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